



SILICON GENERAL PURPOSE DIODE AXIAL LEAD



CT282 TO CT287 40V to 325V, 0.2A

500mW

DO- 35 Glass Axial Package

FEATURES

General IPurpose, Industrial, Military And Space Application, Hermetically Sealed Glass With A Stud On Either Side Of The Glass Passivated Chip Provides Excellent Stability Extremely Low Leakave And Very High Reliability.

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	СТ	СТ	СТ	СТ	СТ	СТ	UNIT
		282	283	284	285	286	287	
Peak Repetitive Reverse Voltage	V _{RRM}	40	80	150	200	250	325	V
Reverses Voltage (Continuous)	V _R	36	70	130	180	225	300	V
Repetivive Peak Forward Current	I _{FM}			650				mA
Non Repetitive Peak Surge	I _{FSM}			2				Α
Current (8.3ms)								
Average Rectified Current	l _o *							
T _A = 25°C T _A = 150°C		200						mA
			50					
Operating And Storage Junction	T _i , T _{sta}		-65	5 to +2	200			°C
Temperature Range								
Power Dissipation	P _D			500				mW

Derate At 1.2mA DC/°C Between Ambient Temperatures of 25° C and 150°C Derate At 1.0mA DC/°C Between Ambient Temperatures of 150° C and 200°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

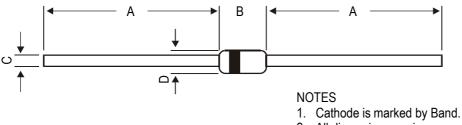
DESCRIPTION	SYMBOL	TEST CONDITION	VALUE	UNIT
Forward Voltage	V _F	I _F =100mA DC,P _W =10ms	<1	V
		Duty Cycle 2% Max		
Reverse Current	I _R	V _R =V _R (Continuous)	<25	nA
		V _R =V _R (Continuous),		
		T _A =150°C	<5	μΑ
Breakdown Voltage	V _{BR}	I _R =100μΑ		
-	Г282		>40	V
C	Г283		>80	V
C	Г284		>150	V
C	Г285		>200	V
C	Г286		>250	V
C	Г287		>325	V
DESCRIPTION	SYMBOL	TEST CONDITION	VALUE	UNIT
Diode Capacitance	C _d	V _R =10V		
	ALL	typ	2	pF
* Pulse Width < 300µs, Duty Cyo	cle < 2%			

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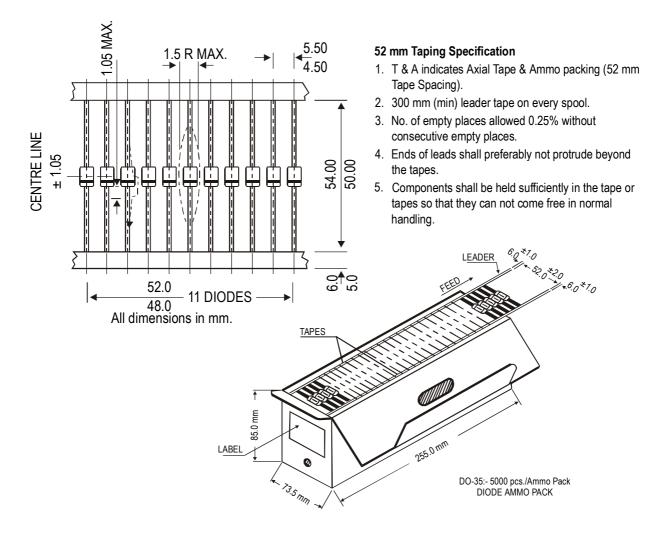
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2. All dimensions are in mm.

DIM	MIN	МАХ
Α	25.40	—
В	3.03	4.44
С	0.46	0.56
D	1.52	2.29

DO-35, 52mm Taping Specification



On request also available in 26 mm Tape and Ammo Pack

Packing Detail

PACKAGE	STAND	ARD PACK	INNER CARTON BOX		OUTER CARTON BOX			
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt	
DO-35 T&A	5K/ammo box	0.88 kg/5K pcs	10" x 3.5" x 3.5"	5K	12.7" x 12.7" x 20"	125K	25 kgs	

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Disclaimer

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